

PSMN2R3-100SSE

N-channel 100 V, 2.3 mOhm MOSFET with enhanced SOA in LFPAK88

16 December 2022

Product data sheet

1. General description

N-channel enhancement mode MOSFET in a LFPAK88 package qualified to 175 °C. Part of Nexperia's "ASFETs for hotswap" portfolio, the PSMN2R3-100SSE delivers very low R_{DSon} and a very strong linear-mode (SOA) performance in a high-reliability copper-clip LFPAK88 package.

PSMN2R3-100SSE complements the latest "hot-swap" controllers - robust enough to withstand substantial inrush currents during turn-on, low R_{DSon} to minimize I^2R losses and deliver optimum efficiency when turned fully ON.

2. Features and benefits

- Fully optimized Safe Operating Area (SOA) for superior linear mode operation
- Low R_{DSon} for low I²R conduction losses
- LFPAK88 package for applications that demand the highest performance and reliability

3. Applications

- Hot swap
- Load switch
- Soft start
- E-fuse
- Telecommunication systems based on a 48 V backplane/supply rail

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	100	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	255	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	341	W
Tj	junction temperature			-55	-	175	°C
Static charac	teristics						
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; Fig. 11		-	1.8	2.28	mΩ
Dynamic cha	racteristics						
Q_{GD}	gate-drain charge	I _D = 25 A; V _{DS} = 50 V; V _{GS} = 10 V; Fig. 14; Fig. 13		8	27	62	nC
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 50 V; V _{GS} = 10 V; Fig. 13		80	161	242	nC
Avalanche ru	iggedness						
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	I_D = 82 A; V_{sup} ≤ 100 V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; t_p = 137 μs; F_{ig} . $\frac{4}{}$	[1]	-	-	732	mJ



Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Source-drain diode							
Q _r	recovered charge	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; Fig. 18$	[2]	-	68	-	nC

- [1] Protected by 100% test
- [2] includes capacitive recovery

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	S	source		D
3	S	source	0	
4	S	source		G(니芸本)
mb	D	mounting base; connected to drain	1 2 3 4 LFPAK88 (SOT1235)	mbb076 S

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PSMN2R3-100SSE	LFPAK88	plastic, single-ended surface-mounted package (LFPAK88); 4 leads; 2 mm pitch; 8 mm x 8 mm x 1.6 mm body	SOT1235			

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN2R3-100SSE	X2E3S10S

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C	-	100	V
V_{DGR}	drain-gate voltage	25 °C ≤ Tj ≤ 175 °C; RGS = 20 kΩ	-	100	V
V _{GS}	gate-source voltage		-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>	-	341	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	-	255	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>	-	180	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 3	-	1020	А
T _{stg}	storage temperature		-55	175	°C

Symbol	Parameter	Conditions		Min	Max	Unit
Tj	junction temperature			-55	175	°C
$T_{sld(M)}$	peak soldering temperature			-	260	°C
Source-drair	n diode					
Is	source current	T _{mb} = 25 °C		-	255	Α
I _{SM}	peak source current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 ^{\circ}C$		-	1020	Α
Avalanche ru	uggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	I_D = 82 A; $V_{sup} \le 100$ V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; t_p = 137 μs; Fig. 4	[1]	-	732	mJ
I _{AS}	non-repetitive avalanche current	$V_{sup} \le 100 \text{ V}; V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ °C}; R_{GS} = 50 \Omega; Fig. 4$	[1]	-	82	А

[1] Protected by 100% test

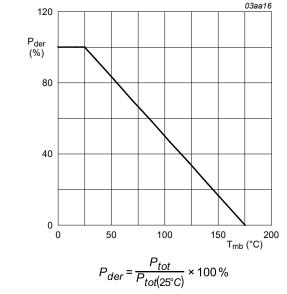
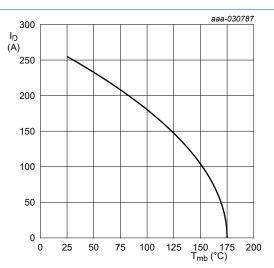
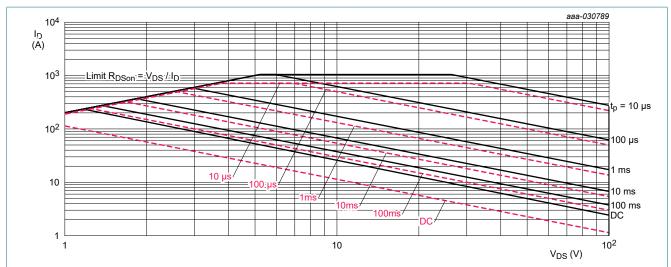


Fig. 1. Normalized total power dissipation as a function of mounting base temperature



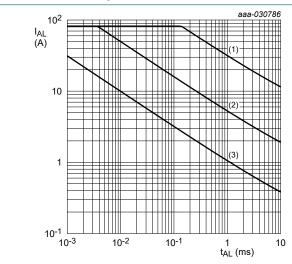
 $V_{GS} \ge 10 \text{ V}$ (1) 255A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

Fig. 2. Continuous drain current as a function of mounting base temperature



 T_{mb} = 25 °C (solid black line); T_{mb} = 125 °C (red dashed line); I_{DM} is a single pulse

Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage



(1) $T_{j \text{ (init)}}$ = 25 °C; (2) $T_{j \text{ (init)}}$ = 150 °C; (3) Repetitive Avalanche

Fig. 4. Avalanche rating; avalanche current as a function of avalanche time

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 5	-	0.2	0.44	K/W
R _{th(j-a)} thermal resistance from junction to ambient	Fig. 6	-	35	-	K/W	
	Fig. 7	-	70	-	K/W	

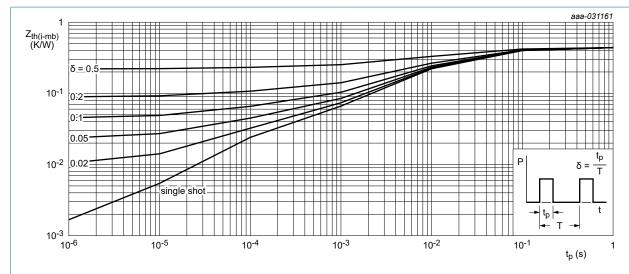
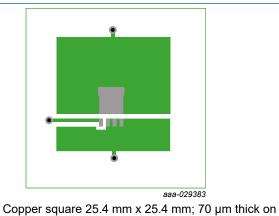
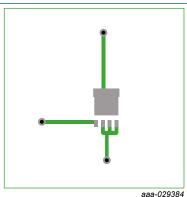


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration



FR4 board

Fig. 6. PCB layout for resistance from junction to



70 µm thick copper on FR4 board

Fig. 7. PCB layout with minimum footprint for thermal resistance from junction to ambient

10. Characteristics

ambient

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	cteristics			'	'	
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	100	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	90	-	-	V
V _{GS(th)}	gate-source threshold	I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 25 °C	2	2.6	3.6	V
	voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C}$	-	3	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C}$	-	1.6	-	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-6.2	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 100 V; V _{GS} = 0 V; T _j = 25 °C	-	0.1	1	μΑ
		V _{DS} = 100 V; V _{GS} = 0 V; T _j = 125 °C	-	20	100	μΑ
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C};$ Fig. 11		-	1.8	2.28	mΩ
		V_{GS} = 10 V; I_D = 25 A; T_j = 100 °C; Fig. 12		-	2.9	3.6	mΩ
		V_{GS} = 10 V; I_D = 25 A; T_j = 175 °C; Fig. 12		-	3.7	5.2	mΩ
R _G	gate resistance	f = 1 MHz; T _j = 25 °C		0.7	1.4	2.8	Ω
Dynamic ch	aracteristics			'			
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 50 V; V _{GS} = 10 V; Fig. 13		80	161	242	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V; <u>Fig. 14</u> ; <u>Fig. 13</u>		-	84	-	nC
Q _{GS}	gate-source charge	I _D = 25 A; V _{DS} = 50 V; V _{GS} = 10 V;		32	54	76	nC
Q _{GS(th)}	pre-threshold gate- source charge	Fig. 14; Fig. 13		-	34	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge			-	20	-	nC
Q _{GD}	gate-drain charge			8	27	62	nC
$V_{GS(pl)}$	gate-source plateau voltage	I _D = 25 A; V _{DS} = 50 V; <u>Fig. 14</u> ; <u>Fig. 13</u>		-	4.7	-	V
C _{iss}	input capacitance	V _{DS} = 50 V; V _{GS} = 0 V; f = 0.5 MHz;		7380	12300	17200	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 16</u>		1600	2670	4300	pF
C _{rss}	reverse transfer capacitance			4	36	94	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 50 \text{ V}; R_L = 2 \Omega; V_{GS} = 10 \text{ V};$		-	41	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$		-	41	-	ns
t _{d(off)}	turn-off delay time			-	88	-	ns
t _f	fall time			-	54	-	ns
Source-drai	in diode						
V _{SD}	source-drain voltage	$I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}; Fig. 17$		-	0.8	1	V
t _{rr}	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$		-	56	-	ns
Q _r	recovered charge	V _{DS} = 50 V; <u>Fig. 18</u>	[1]	-	68	-	nC

^[1] includes capacitive recovery

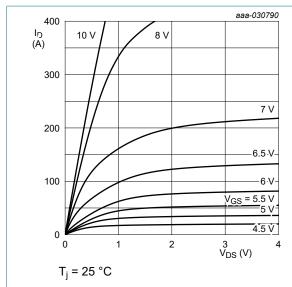


Fig. 8. Output characteristics; drain current as a function of drain-source voltage; typical values

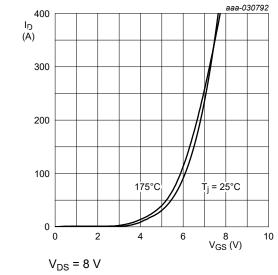


Fig. 10. Transfer characteristics; drain current as a function of gate-source voltage; typical values

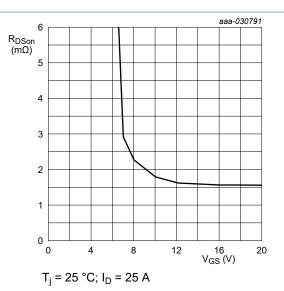


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

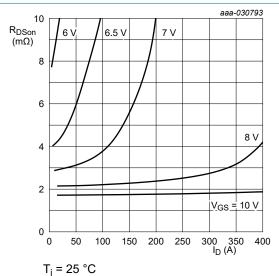
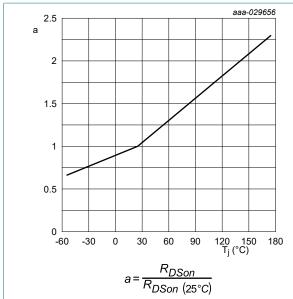


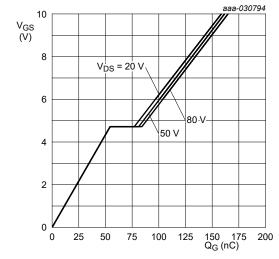
Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

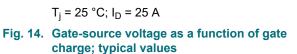


V_{GS(pl)}
V_{GS(th)}
V_{GS}
Q_{GS1}
Q_{GS2}
Q_{GG(tot)}
003aaa508

Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

Fig. 13. Gate charge waveform definitions





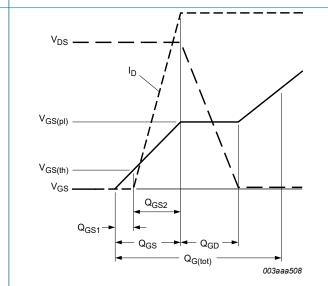


Fig. 15. Gate charge waveform definitions

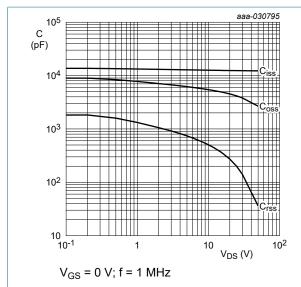
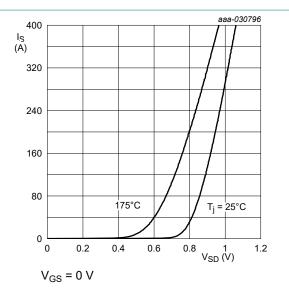


Fig. 16. Input, output and reverse transfer capacitances | Fig. 17. Source-drain (diode forward) current as a as a function of drain-source voltage; typical values



function of source-drain (diode forward) voltage; typical values

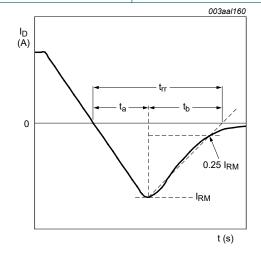


Fig. 18. Reverse recovery timing definition

11. Package outline

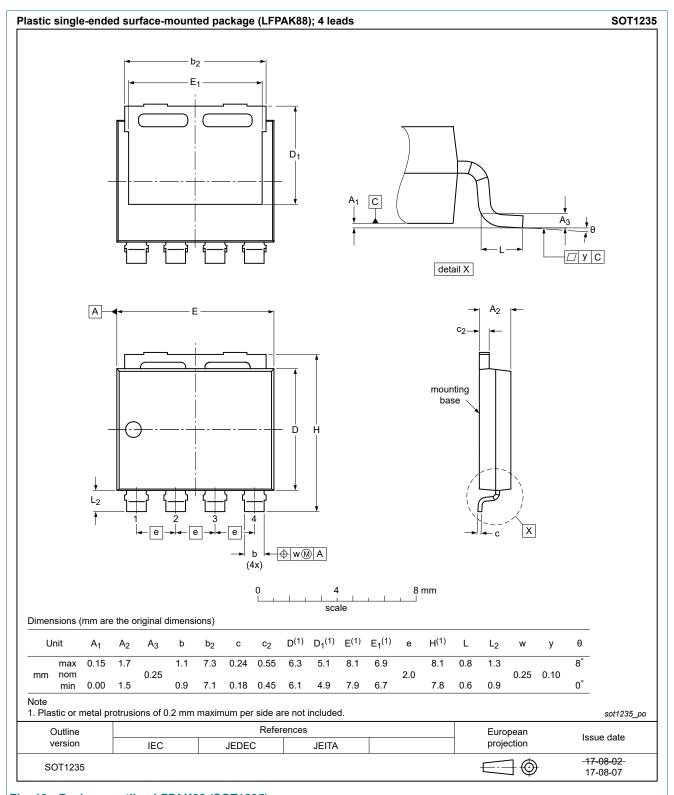
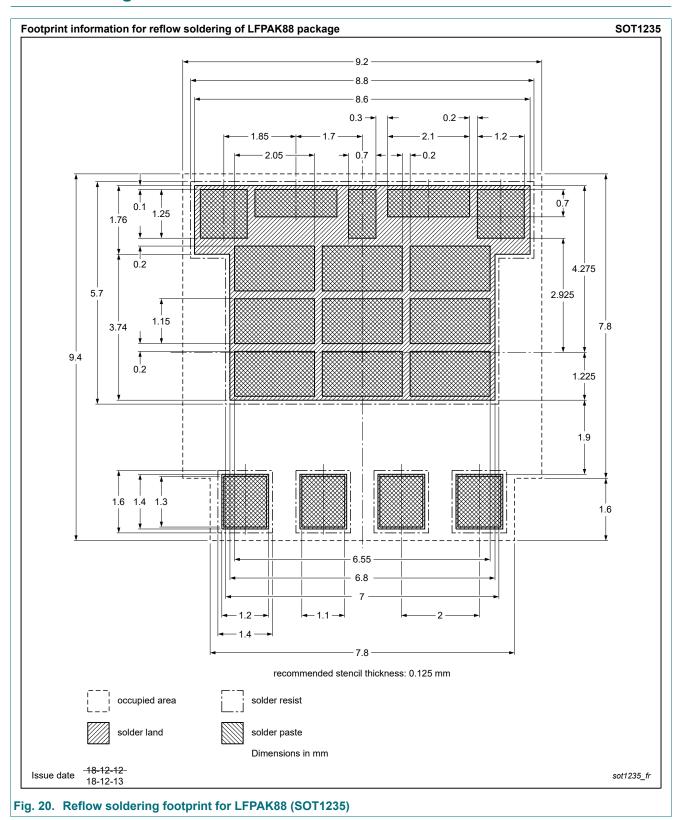


Fig. 19. Package outline LFPAK88 (SOT1235)

12. Soldering



13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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